2.5V Drive Nch MOSFET

RTF025N03

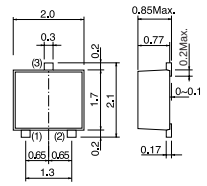
●Structure
Silicon N-channel MOSFET

●Features
1) Low On-resistance.
2) Space saving, small surface mount package (TUMT3).
3) Low voltage drive (2.5V drive).

●Applications
Switching

●Dimensions (Unit : mm)

TUMT3



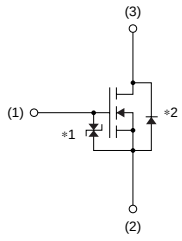
(1) Gate
(2) Source
(3) Drain

Abbreviated symbol : PL

●Packaging specifications

Type	Package	Taping
	Code	TL
	Basic ordering unit (pieces)	3000
RTF025N03		○

●Inner circuit



*1 ESD PROTECTION DIODE
*2 BODY DIODE

(1) Gate
(2) Source
(3) Drain

●Absolute maximum ratings (Ta=25°C)

Parameter		Symbol	Limits	Unit
Drain-source voltage		V_{DSS}	30	V
Gate-source voltage		V_{GSS}	12	V
Drain current	Continuous	I_D	±2.5	A
	Pulsed	I_{DP} *1	±10	A
Source current (Body diode)	Continuous	I_S	0.6	A
	Pulsed	I_{SP} *1	10	A
Total power dissipation		P_D *2	0.8	W
Channel temperature		Tch	150	°C
Range of storage temperature		Tstg	−55 to +150	°C

*1 Pw≤10μs, Duty cycle≤1%
*2 Mounted on a ceramic board

●Thermal resistance

●**Electrical characteristics** (Ta=25°C)

Parameter	Symbol	Min.	Typ.	Max.	Unit	Conditions
Gate-source leakage	I_{GSS}	–	–	10	μA	V_{GS}=12V, V_{DS}=0V
Drain-source breakdown voltage	$V_{(BR)\ DSS}$	30	–	–	V	I_D= 1mA, V_{GS}=0V
Zero gate voltage drain current	I_{DSS}	–	–	1	μA	V_{DS}= 30V, V_{GS}=0V
Gate threshold voltage	$V_{GS\ (th)}$	0.5	–	1.5	V	V_{DS}= 10V, I_D= 1mA
Static drain-source on-state resistance	$R_{DS\ (on)}$*	–	48	67	mΩ	I_D= 2.5A, V_{GS}= 4.5V
		–	50	70	mΩ	I_D= 2.5A, V_{GS}= 4V
		–	70	98	mΩ	I_D= 2.5A, V_{GS}= 2.5V
Forward transfer admittance	$\|Y_{fs}\|$ *	2	–	–	S	V_{DS}= 10V, I_D= 2.5A
Input capacitance	C_{iss}	–	270	–	pF	V_{DS}= 10V
Output capacitance	C_{oss}	–	70	–	pF	V_{GS}=0V
Reverse transfer capacitance	C_{rss}	–	40	–	pF	f=1MHz
Turn-on delay time	$t_{d\ (on)}$ *	–	8	–	ns	V_{DD}≒ 15V I_D= 1.25A V_{GS}= 4.5V R_L=12Ω R_G=10Ω
Rise time	t_r *	–	15	–	ns	
Turn-off delay time	$t_{d\ (off)}$ *	–	27	–	ns	
Fall time	t_f *	–	11	–	ns	
Total gate charge	Q_g *	–	3.7	5.2	nC	V_{DD}≒15V
Gate-source charge	Q_{gs} *	–	0.7	–	nC	V_{GS}= 4.5V
Gate-drain charge	Q_{gd} *	–	1.2	–	nC	I_D= 2.5A

*Pulsed

●**Body diode characteristics** (Source-drain) (Ta=25°C)

Parameter	Symbol	Min.	Typ.	Max.	Unit	Conditions
Forward voltage	V_{SD}	–	–	1.2	V	I_S= 0.6A, V_{GS}=0V

Notes

- No technical content pages of this document may be reproduced in any form or transmitted by any means without prior permission of ROHM CO.,LTD.
- The contents described herein are subject to change without notice. The specifications for the product described in this document are for reference only. Upon actual use, therefore, please request that specifications to be separately delivered.
- Application circuit diagrams and circuit constants contained herein are shown as examples of standard use and operation. Please pay careful attention to the peripheral conditions when designing circuits and deciding upon circuit constants in the set.
- Any data, including, but not limited to application circuit diagrams information, described herein are intended only as illustrations of such devices and not as the specifications for such devices. ROHM CO.,LTD. disclaims any warranty that any use of such devices shall be free from infringement of any third party's intellectual property rights or other proprietary rights, and further, assumes no liability of whatsoever nature in the event of any such infringement, or arising from or connected with or related to the use of such devices.
- Upon the sale of any such devices, other than for buyer's right to use such devices itself, resell or otherwise dispose of the same, no express or implied right or license to practice or commercially exploit any intellectual property rights or other proprietary rights owned or controlled by
- ROHM CO., LTD. is granted to any such buyer.
- Products listed in this document are no antiradiation design.

The products listed in this document are designed to be used with ordinary electronic equipment or devices (such as audio visual equipment, office-automation equipment, communications devices, electrical appliances and electronic toys).
Should you intend to use these products with equipment or devices which require an extremely high level of reliability and the malfunction of with would directly endanger human life (such as medical instruments, transportation equipment, aerospace machinery, nuclear-reactor controllers, fuel controllers and other safety devices), please be sure to consult with our sales representative in advance.

About Export Control Order in Japan

Products described herein are the objects of controlled goods in Annex 1 (Item 16) of Export Trade Control Order in Japan.
In case of export from Japan, please confirm if it applies to "objective" criteria or an "informed" (by MITI clause) on the basis of "catch all controls for Non-Proliferation of Weapons of Mass Destruction.